



Shanghai Lunsure Electronic
Technology Co.,Ltd
Tel:0086-21-37185008
Fax:0086-21-57152769

BAT46

Small Signal Schottky Diode

Features

- For general purpose applications
- These diodes features very low-turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.

Maximum Ratings

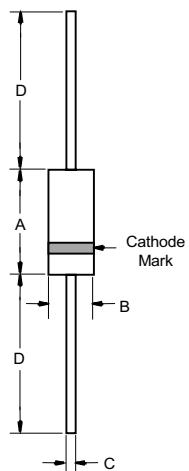
- Operating Temperature: -55°C to +125°C
- Storage Temperature: 55°C to +150°C
- Maximum Thermal Resistance; 300°C/W Junction To Ambient

Electrical Characteristics @ 25°C Unless Otherwise Specified

Repetitive Peak Reverse Voltage	V_{RRM}	100V	
Forward continuous Current	I_F	150mA ¹⁾	$T_A = 25^\circ C$
Power Dissipation	P_{TOT}	150mW ¹⁾	$T_A = 65^\circ C$
Junction Temperature	T_J	125°C	
Peak Forward Surge Current	I_{FSM}	750mA ¹⁾	$T_p < 10ms, T_A = 25^\circ C$
Forward voltage pulse Test $t_p < 300\mu S$, at $V_R = 10V$, $T_J = 60^\circ C$, $\delta < 2\%$	V_F	0.25V 0.45V 1V	$I_F = 0.1mA$ $I_F = 10mA$ $I_F = 250mA$
Leakage current pulse test $t_p < 300\mu S$, $\delta < 2\%$	I_R	0.5μA 0.8μA 2μA 5μA	$V_R = 1.5V$ $V_R = 10V$ $V_R = 50V$ $V_R = 75V$
Typical Junction Capacitance	C_J	6pF	Measured at 1.0MHz, $V_R = 1V$
Reverse Recovery Time	T_{rr}	5nS	$I_F = 10mA$ $V_R = 6V$ $R_L = 100\Omega$

1) Valid provided that electrodes are kept at ambient temperature

DO-35



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	---	.166	---	4.2	
B	---	.079	---	2.00	
C	---	.020	---	.52	
D	1.000	---	25.40	---	

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Figure 1. Forward current versus forward voltage at different temperatures(typical values)

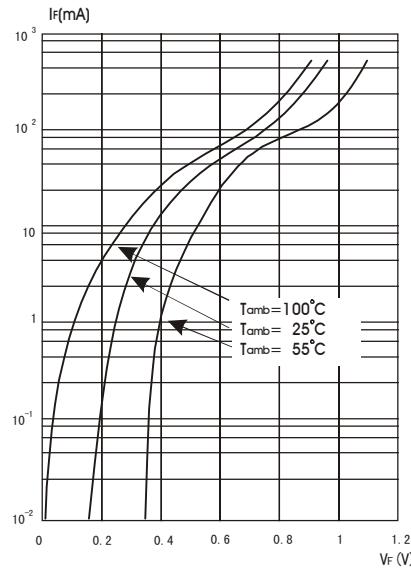


Figure 2. Forward current versus forward voltage (typical values)

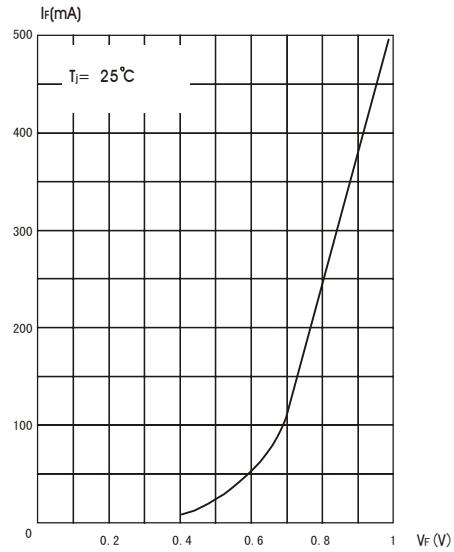
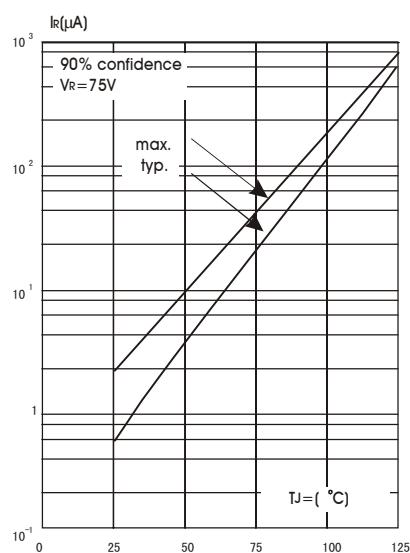


Figure 3. Reverse current versus junction temperature (typical values)



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Figure 4.Reverse current versus continuous
Reverse voltage

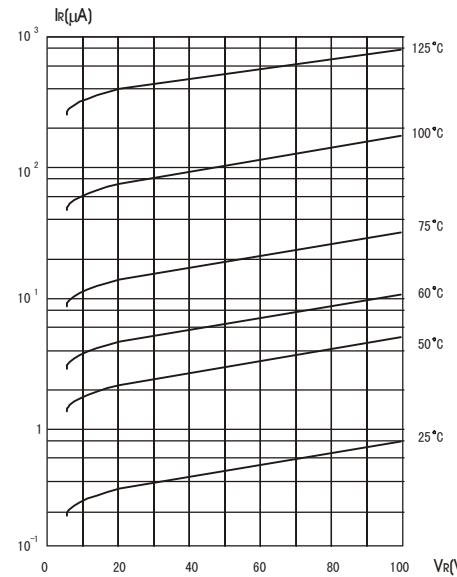


Figure 5.Capacitance C versus reverse applied
voltage V_R (typical values)

